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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
10/083,353	02/27/2002	Ken Yoshioka	503.38156VX1	1842	
20457 75	590 09/01/2004		EXAM	EXAMINER	
ANTONELLI, TERRY, STOUT & KRAUS, LLP			MOORE, KARLA A		
1300 NORTH S SUITE 1800	SEVENTEENTH STREET		ART UNIT	PAPER NUMBER	
	VA 22209-9889		1763		
			DATE MAILED: 09/01/2004	4	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)			
		10/083,353	YOSHIOKA ET AL.			
	Office Action Summary	Examiner	Art Unit			
		Karla Moore	1763			
Period fo	The MAILING DATE of this communication apports.	pears on the cover sheet with the c	correspondence address			
A SH THE - Exte after - If the - If NO - Failu Any	ORTENED STATUTORY PERIOD FOR REPL' MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reply operiod for reply is specified above, the maximum statutory period vertoe reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be tin y within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from , cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).			
Status						
1) 又	Responsive to communication(s) filed on 16 Ju	ılv 2004				
2a)□	his action is FINAL . 2b)⊠ This action is non-final.					
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposit	ion of Claims					
5)□ 6)⊠ 7)□	Claim(s) <u>1-3</u> is/are pending in the application. 4a) Of the above claim(s) is/are withdraw Claim(s) is/are allowed. Claim(s) <u>1-3</u> is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/o					
Applicati	on Papers					
10)	The specification is objected to by the Examine The drawing(s) filed on is/are: a) accomplicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Examine	epted or b) objected to by the liderawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).			
Priority ι	ınder 35 U.S.C. § 119					
12)[a)[Acknowledgment is made of a claim for foreign All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority application from the International Bureau See the attached detailed Office action for a list	s have been received. s have been received in Applicationity documents have been received in Proceived in Pro	on No ed in this National Stage			
2) Notic 3) Inform	t(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) r No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:				
i ape	, 110(0) Mail Date	o) [_] Oulel				

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DETAILED ACTION

This office action is meant to replace the office action mailed 16 June 04.

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claim 1 is rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,769,952 to Komino in view of U.S. Patent No. 5,334,251 to Nashimoto and U.S. Patent No. 6,048,435 to DeOrnellas et al.
- This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 4. Komino discloses an apparatus for processing a specimen substantially as claimed and comprising: an etching process unit (Figure 1, 10A-C; column 5, rows 48-59), which is supplied with a gas to produce plasma (column 12, rows 9-12); a rinsing unit (18A and 18C; column 6, rows 7-10); and a dryer unit (18B and 18D; column 5, rows 48-59) for drying. Komino further teaches that the operations in the etching process unit and the

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rinsing and/or drying unit can take place in succession (column 6, rows 10-20).

Additionally, the apparatus of Komino may be constructed to comprise plural deposition units, which may be used continuously, along with the etching, rinsing and drying units (column 5, rows 48-51). This fairly suggests that the apparatus would be capable of processing a substrate with multiple layers.

- 5. However, Komino fail to explicitly teach the apparatus capable of processing a specimen while controlling the temperature of the substrate.
- 6. Nashimoto teaches the use of a temperature control mechanism for semiconductor processing apparatus for the purpose accurately controlling the temperature of a substrate during processing because the results of processing may depend largely upon the temperature of the substrate being processed (column 1, rows 20-26; column 1, row 55 through column 2, rows 13 and column 5, row 56 through column 6, row 14).
- 7. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a temperature control mechanism in any of the types of substrate processing apparatus (etching, rinsing, drying) in Komino in order to accurately control the temperature of the substrate during processing because results of processing may depend largely upon the temperature of the substrate being processed as taught by Nashimoto.
- 8. Examiner notes that the specific temperature to which a process is controlled is a processing parameter that would depend on the type of processing, type of substrate and type of processing material being used. One of ordinary skill in the art would immediately recognize that, depending on the intended processing method, ideal-processing conditions would need to be established. Regarding the article to be worked

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upon and the specific composition of the layer on the substrate, the courts have ruled that the inclusion of material or article worked upon by a structure being claimed does not impart patentability to the claims. In re Young, 75 F. 2d 966, 25 USPQ 69 (CCPA 1935) (as restated in In re Otto, 312 F. 2d 937, 136 USPQ 458, 459 (CCPA 1963)). Also, regarding the processing materials, the courts have ruled that expressions relating the apparatus to contents thereof during an intended operation are of no significance in determining patentability of the apparatus claim. Ex parte Thibault, 164 USPQ 666, 667 (Bd. App. 1969). Further, with respect to the inclusion of these aforementioned method limitations, the courts have ruled that the courts have ruled that a claim containing a "recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus" if the prior art apparatus teaches all the structural limitations of the claim. Ex parte Masham, 2 USPQ2d 1647 (Bd. Pat. App. & Inter. 1987).

- 9. In addition with respect to the invention of claim 1, Komino further fails to specifically teach that the etching apparatus is capable of supplying a low pressure, high density, low ion energy plasma.
- DeOrnellas et al. teach using a low pressure, high density, and low ion energy plasma for delivering superior etching results (column 4, rows 43-67).
- It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided an apparatus capable of plasma processing conditions such as low pressure, high density and low ion energy in Komino in order to deliver superior etching results which are required for the latest semiconductor products as taught by DeOrnellas et al.

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- Claims 2 and 3 are rejected under 35 U.S.C. 103(a) as being unpatentable over Komino and DeOrnellas et al. as applied to claim 1 above, and further in view of U.S. Patent No. 5,303,671 to Kondo et al. and Japanese Patent No. 60-183996 to Kameyama.
- 13. Komino and DeOrnellas et al. disclose the invention substantially as claimed and as described above.
- 14. Additionally, Komino discloses: an atmospheric loader (20); a vacuum transport chamber (14) having a vacuum transport robot (16) therein; and unload and loadlock chambers (130A and 130B) connecting between said atmospheric loader and said vacuum transport chamber for delivering the specimen via an atmospheric transport unit (22), wherein said vacuum transport chamber is connected to all of the etching process chambers of said etching process unit, and said atmospheric loader is connected via said atmospheric transport unit to said rinsing unit and drying unit.
- 15. With respect to claim 3, Komino teaches that any number of the three processing chambers, 10A-C, may be etching chambers (column 5, rows 48-59).
- 16. However, Komino and DeOrnellas et al. fail to teach a rinsing cup in the rinsing unit and a hot plate in the drying unit.
- 17. Kondo et al. teach the use of a hot plate for the purpose of heating/drying a specimen after washing (column 8, rows 28-30).
- 18. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a hot plate in the drying unit of Komino in order to heat/dry a specimen after washing as taught by Kondo et al.

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19. Kameyama teaches the use of a rinsing cup for the purpose of reducing the adhesion of dust, to use only a small amount of treating liquid and to equalize the extent of a treatment (purpose and constitution).

20. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a rinsing cup in the rinsing unit of Komino in order to reduce adhesion of dust, use only a small amount of treating liquid and to equalize the extent of treatment as taught by Kameyama.

Response to Arguments

- 20. Applicant's arguments, see Paper No. 9, filed 11/25/03, with respect to the rejection(s) of claim(s) 1-3, using a reference that has a filing date after the present application's priority date and therefore is not considered prior art, have been fully considered and are persuasive. Therefore, the rejection has been withdrawn. However, upon further consideration, a new ground(s) of rejection is made in view of Nashimoto and DeOrnellas et al., which does has a valid prior art date and provide similar teachings. Nashimoto fairly teaches controlling a temperature of a substrate during processing to an ideal temperature appropriate for an intended method, workpiece and processing materials. DeOrnellas et al. fairly teach using an apparatus capable of supplying a low pressure, high density, and low ion energy plasma for processing current semiconductor technology.
- 21. Examiner would like to again note that the present invention is drawn to an apparatus, not a method. If Applicant wishes to claim an invention drawn to a method of using the apparatus or a method of processing using specific materials, Applicant should

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file a related application. In the present Application, prior art that is capable of Applicant's intended uses will continue to be applied.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Karla Moore whose telephone number is 571.272.1440. The examiner can normally be reached on Monday-Friday, 8:30am-5:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Gregory Mills can be reached on 571.272.1439. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

18 August 2004

P. Mussanzadel
Parviz Hassanzadeh
Primary Examiner

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